

Description

The AP70P03D uses advanced trench technology

to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 4.5V. This

device is suitable for use as a

Battery protection or in other Switching application.

General Features

 $V_{DS} = -30V I_{D} = -70 A$

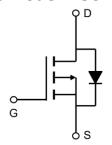
 $R_{DS(ON)} < -7.5 \text{ m}\Omega$ @ V_{GS} =-10V

Application

Battery protection

Load switch

Uninterruptible power supply







Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
AP70P03 D	TO-252-3L	AP70P03D XXX YYYY	2500

Absolute Maximum Ratings (TC=25°C unless otherwise specified)

Symbol	Parameter	Rating	Units
VDS	Drain-Source Voltage	-30	V
Vgs	Gate-Source Voltage	±20	V
I _D @T _C =25°C	Continuous Drain Current, V _{GS} @ -10V ^{1,6}	-70	А
I _D @T _C =100°C	Continuous Drain Current, V _{GS} @ -10V ^{1,6}	-50	Α
Ідм	Pulsed Drain Current ²	-200	А
EAS	Single Pulse Avalanche Energy ³	80	mJ
las	Avalanche Current	-40	Α
P _D @T _C =25°C	Total Power Dissipation ⁴	90	W
Тѕтс	Storage Temperature Range	-55 to 175	°C
TJ	Operating Junction Temperature Range	-55 to 175	°C
Reja	Thermal Resistance Junction-ambient ¹(t≦10S)	20	°C/W
	Thermal Resistance Junction-ambient ¹ (Steady State)	50	°C/W
Rejc	Thermal Resistance Junction-case ¹	1.6	°C/W



Electrical Characteristics (T_J=25 °C, unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
BVDSS	Drain-Source Breakdown Voltage V _{GS} =0V , I _D =-250uA		-30			V
		V _{GS} =-10V , I _D =-20A		6	7.2	mΩ
Rds(on)	Static Drain-Source On-Resistance ²	V _{GS} =-4.5V , I _D =-15A		9.5	12	mΩ
V _{GS(th)}	Gate Threshold Voltage	V _{GS} =V _{DS} , I _D =-250uA			-2.5	V
		V _{DS} =-24V , V _{GS} =0V , T _J =25℃	, TJ=25°C1		-1	
IDSS	Drain-Source Leakage Current	V _{DS} =-24V , V _{GS} =0V , T _J =55℃			-5	uA
Igss	Gate-Source Leakage Current	V _{GS} =±20V , V _{DS} =0V			±100	nA
Rg	Gate Resistance	V _{DS} =0V , V _{GS} =0V , f=1MHz		1.2		Ω
Qg	Total Gate Charge (-10V)			60		
Qgs	Gate-Source Charge	rce Charge V _{DS} =-15V , V _{GS} =-10V				nC
Qgd	Gate-Drain Charge	─ I _D =-18A		15		
Td(on)	Turn-On Delay Time			17		
Tr	Rise Time	V _{DD} =-15V V _{GS} =-10V		40		
Td(off)	Turn-Off Delay Time	R _G =3.3 Ω,		55		ns
T _f	Fall Time	I _D =-20A		13		
Ciss	Input Capacitance			3450		
Coss	Output Capacitance	── V _{DS} =-25V , V _{GS} =0V , f=1MHz		255		pF
Crss	Reverse Transfer Capacitance			140		
ls	Continuous Source Current ^{1,5}	V _G =V _D =0V , Force Current			-70	Α
VsD	Diode Forward Voltage ²	V _{GS} =0V , I _S =-1A , T _J =25℃			-1.2	V
trr	Reverse Recovery Time	IF=-20A , di/dt=100A/μs ,		22		nS
Q _{rr}	Reverse Recovery Charge	T=25℃		72		nC

Note:

- 1.The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper.
- 2. The data tested by pulsed , pulse width \leq 300us , duty cycle \leq 2%
- 3. The EAS data shows Max. rating . The test condition is V_{DD} =-50V, V_{GS} =-10V, L=0.1mH, I_{AS} =-40A
- 4.The power dissipation is limited by 150°C junction temperature
- 5. The data is theoretically the same as I_D and I_{DM} , in real applications, should be limited by total power dissipation
- 6. The maximum current rating is package limited.



Typical Characteristics

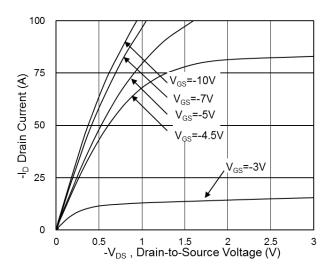


Fig.1 Typical Output Characteristics

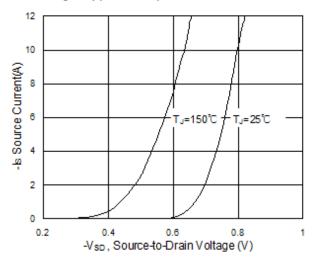


Fig.3 Forward Characteristics of Reverse

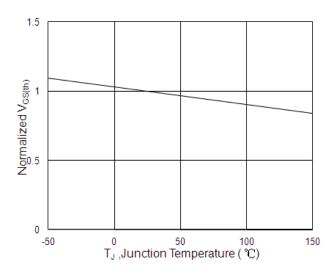


Fig.5 Normalized -V_{GS(th)} vs. T_J

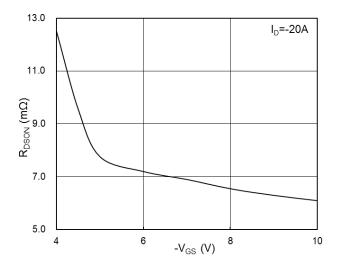


Fig.2 On-Resistance vs. Gate-Source Voltage

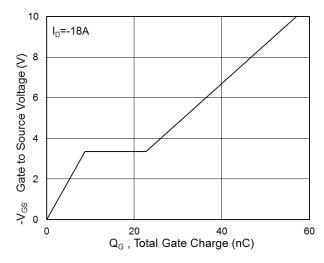


Fig.4 Gate-Charge Characteristics

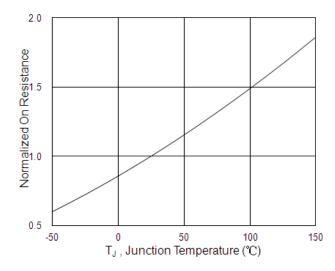
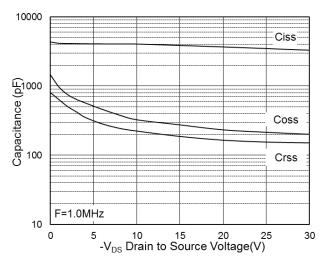


Fig.6 Normalized R_{DSON} vs. T_J







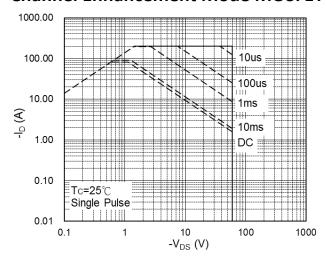


Fig.7 Capacitance

Fig.8 Safe Operating Area

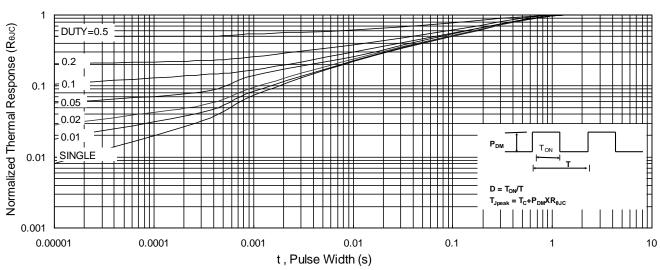


Fig.9 Normalized Maximum Transient Thermal Impedance

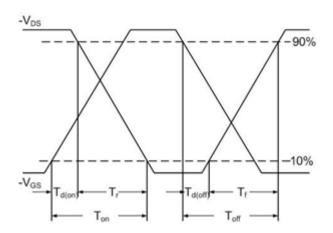


Fig.10 Switching Time Waveform

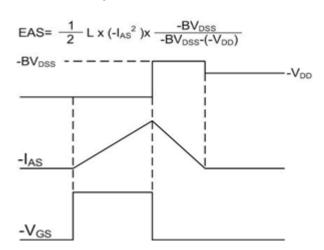
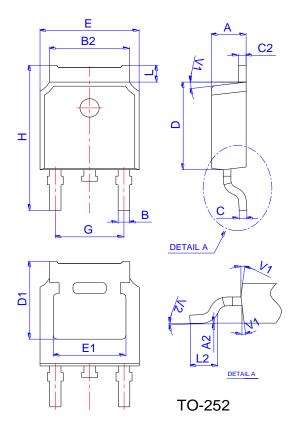


Fig.11 Unclamped Inductive Switching Waveform

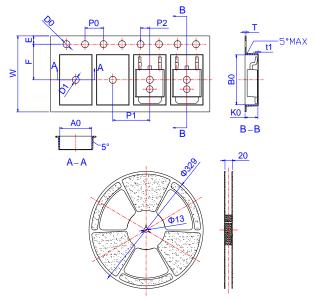


Package Mechanical Data



	Dimensions					
Ref.	Millimeters			Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	2.10		2.50	0.083		0.098
A2	0		0.10	0		0.004
В	0.66		0.86	0.026		0.034
B2	5.18		5.48	0.202		0.216
С	0.40		0.60	0.016		0.024
C2	0.44		0.58	0.017		0.023
D	5.90		6.30	0.232		0.248
D1	5.30REF			0.209REF		
E	6.40		6.80	0.252		0.268
E1	4.63			0.182		
G	4.47		4.67	0.176		0.184
Н	9.50		10.70	0.374		0.421
L	1.09		1.21	0.043		0.048
L2	1.35		1.65	0.053		0.065
V1		7°			7°	
V2	0°		6°	0°		6°

Reel Spectification-TO-252



	Dimensions					
Ref.	Millimeters			Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.
W	15.90	16.00	16.10	0.626	0.630	0.634
E	1.65	1.75	1.85	0.065	0.069	0.073
F	7.40	7.50	7.60	0.291	0.295	0.299
D0	1.40	1.50	1.60	0.055	0.059	0.063
D1	1.40	1.50	1.60	0.055	0.059	0.063
P0	3.90	4.00	4.10	0.154	0.157	0.161
P1	7.90	8.00	8.10	0.311	0.315	0.319
P2	1.90	2.00	2.10	0.075	0.079	0.083
A0	6.85	6.90	7.00	0.270	0.271	0.276
В0	10.45	10.50	10.60	0.411	0.413	0.417
K0	2.68	2.78	2.88	0.105	0.109	0.113
Т	0.24		0.27	0.009		0.011
t1	0.10			0.004		
10P0	39.80	40.00	40.20	1.567	1.575	1.583



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